UNCLASSIFIED

Defense Technical Information Center
Compilation Part Notice

ADP011932

TITLE: Relaxation Dynamics of Excited States of Er[3+] in YVO4 Single Crystals

DISTRIBUTION: Approved for public release, distribution unlimited

This paper is part of the following report:

To order the complete compilation report, use: ADA399287

The component part is provided here to allow users access to individually authored sections of proceedings, annals, symposia, etc. However, the component should be considered within the context of the overall compilation report and not as a stand-alone technical report.

The following component part numbers comprise the compilation report:
ADP011865 thru ADP011937
Relaxation dynamics of excited states of Er$^{3+}$ in YVO$_4$ single crystals

S.Gołąb$^a$, G.Dominiak-Dzik$^a$, P.Solarza$^a$, T.Łukasiewicz$^b$, M.Świrkowicz$^b$, I. Sokólska$^a$, W.Ryba-Romanowski$^a$

$^a$ Institute of Low Temperature and Structure Research, Polish Academy of Sciences, Okólna 2 Street, 50-950 Wrocław, Poland
$^b$ Institute of Electronic Materials Technology, Wólczyńska 133 Street, 01-919 Warsaw, Poland

ABSTRACT

Crystals of Er:YVO$_4$ were grown by Czochralski method. Uniformly doped and good quality crystals have been obtained. The lifetimes of the $^4$S$_3/2$, and the luminescence dynamics were studied as a function of temperature in the region 5-500K. The green luminescence around 550 nm has been observed in excitation by the Ti:sapphire laser into $^4$I$_{13/2}$ level. The excitation spectrum recorded for $^4$S$_3/2$ has been compared with absorption cross section spectrum and calculated ESA spectrum for $^4$I$_{11/2}$-$^4$F$_{9/2}$ transition. The contribution of ESA process in upconversion phenomenon under excitation into $^4$I$_{11/2}$ has been assessed. The emission cross- section and the gain coefficient for $^4$I$_{13/2}$-$^4$I$_{15/2}$ transition of Er$^{3+}$ in YVO$_4$ have been calculated.

Keywords: Er:YVO$_4$ crystals, absorption spectrum, green luminescence, doping.

1. INTRODUCTION

In the last few years Er$^{3+}$ doped YVO$_4$ has been considered as a potential laser material in the IR spectral region $^1$. However, that real potential strongly depends on the relaxation dynamics of excited states to lower states and upconversion processes. For Er:YVO$_4$ the ESA and SE cross-section spectra for $^4$I$_{13/2}$-$^4$I$_{15/2}$ the transition do not overlap $^2$. Accordingly, losses of radiation by ESA at potential laser transition should be negligible but no laser emission of Er$^{3+}$:YVO$_4$ has been observed yet. The absorption spectra, emission spectra and fluorescence dynamics of Er$^{3+}$:YVO$_4$ have been reported$^3$. Upconverted green luminescence has been observed by excitation into $^4$F$_{9/2}$, $^4$I$_{9/2}$ and $^4$I$_{11/2}$ $^1$. The absorption cross-section (e$_{ESA}$) from $^4$I$_{13/2}$ level of Er:YVO$_4$ have been determined experimentally $^3$. In this study, the temperature dependence of $^4$S$_3/2$ decay in the range 5-500K was investigated and compared with predictions of multiphonon relaxation model. The contribution of ESA process to the upconversion phenomenon under excitation into $^4$I$_{11/2}$ was considered. The emission cross- section and the gain coefficient for $^4$I$_{13/2}$-$^4$I$_{15/2}$ transition of Er$^{3+}$ in YVO$_4$ were calculated.

2. EXPERIMENTAL

Crystals of Er:YVO$_4$ were grown by Czochralski method. Uniformly doped and good quality crystals have been obtained. The concentration of Er$^{3+}$ in the crystals studied was 0.5, 2, and 4 at %. Absorption spectra were measured with a Varian model 2300 absorption spectrophotometer. The sample luminescence was exited by a Ti:sapphire laser emitting at 970 nm or by Continuum OPO model Surelite I pumped by third harmonic of Nd:YAG laser and dispersed by 1m double grating monochromator, detected by photomultiplier or InSb detector and analysed by a Stanford Model SRS 250 Boxcar integrator. In luminescence decay measurements a digital oscilloscope Tektronix model 3052 has been used. For low temperature measurements, the samples were mounted in Oxford Model CF 1204 continuous flow liquid helium cryostat equipped with a temperature controller.

3. RESULTS AND DISCUSSION

Room temperature absorption spectrum of Er$^{3+}$ ions on YVO$_4$ is shown in Fig.1. The observed absorption lines are not fully resolved and inhomogeneously broadened.
The temperature dependence of luminescence lifetime of the $^4S_{3/2}$ level of $\text{Er}^{3+}$ in $\text{YVO}_4$ for samples containing 0.5 at % and 4 at % of erbium is shown by solid circles and squares respectively in Fig. 2. The samples were excited by OPO at 523 nm into the level $^2H_{11/2}$. The obtained data are consistent with data presented previously for room temperature and at 77K. In the phenomenological approach of Riseberg and Moos the expected temperature dependence of $^4S_{3/2}$ lifetime has been drawn according to the formula:

$$\tau = \frac{12A_0 \left( ^2H_{11/2} \right) \exp \left( -\frac{\Delta E}{kT} \right) + 4A_0 \left( ^4S_{3/2} \right)}{12 \exp \left( -\frac{\Delta E}{kT} \right) + 4 + A_0 \left( \frac{\hbar \omega}{kT} \right) \exp \left( \frac{\hbar \omega}{kT} - 1 \right)}$$

(1)

where: $A_0 \left( ^2H_{11/2} \right)$, $A_0 \left( ^4S_{3/2} \right)$ denote the values of the radiative transition rates as given in $^4I_{15/2}$, $\Delta E = 709 \text{ cm}^{-1}$ is the energy gap between $^2H_{11/2}$ and $^4S_{3/2}$ levels. $A_0$ denotes the spontaneous multiphonon transition rate, $\hbar \omega = 890 \text{ cm}^{-1}$ is the phonon energy and $p = 4$ is the number of phonons needed to cover the energy gap between $^4S_{3/2}$ and $^4F_{9/2}$ levels. $A_0$ has been calculated from the inverse of luminescence lifetime measured and 5K. The solid line in Fig. 2 presents the theoretical approach derived from equation (1). It cannot predict the experimental temperature dependence of lifetime for the $^4S_{3/2}$ level because the experimentally determined lifetime decreases quickly with increasing temperature. The reason of observed discrepancy is not clear yet. This may be caused by interaction of active ions with structural defects.

To elucidate a mechanism of upconversion the excitation spectrum of $^4S_{3/2}$ luminescence was recorded at room temperature. The sample was excited by tuneable Ti:sapphire laser in the range 968-988 nm and detected at 552.5 nm. The resulting excitation spectrum is presented in Fig. 3 by solid line with the $\sigma_{\text{ESA}}$ spectrum (dotted line) in the same wavelength domain. From the analysis of the energy level diagram of $\text{Er}^{3+}$ in $\text{YVO}_4$ presented in $^3$, we have built the $\sigma_{\text{ESA}}$ spectra corresponding to $^4I_{13/2}^1 - ^4F_{9/2}$ transition after pumping around 970 nm using the expression $^7$.
\[ \sigma_{\text{exc}}^\iota\iota (\lambda) = \frac{\lambda S_{\text{exc}} (J - J')}{2J' + 1} \sum_{i=1}^{i_{\text{max}}} \frac{f_i}{\pi \Delta \lambda/2} \left( \frac{\lambda - \lambda_i}{\Delta \lambda/2} \right)^3 \]

where: \( f_i \) is the Boltzmann factor for \( i \)-th crystal field level of the starting multiplet \( J \) of ESA transition. This factor has been approximated by \( 1/(2J+1) \); \( \lambda_i \) are the expected wavelength position of ESA lines. In order to calculate \( \lambda_{\text{exp}} \), the experimentally observed crystal-field energy levels of \( \text{Er}^{3+} \) ion in \( \text{YVO}_4 \) for the \( ^{4}I_{13/2} \) and \( ^{4}F_{7/2} \) were taken from Table 3 in \( ^3 \). \( \Delta \lambda \) is the linewidth of ESA line assumed to have a Lorentzian profile and the same as of GSA line around 970 nm i.e. \( \Delta \lambda = 1 \text{nm} \); \( \lambda \) is the average wavelength of the transition \( \lambda = 9.74 \times 10^{-6} \text{cm} \). \( S_{\text{calc}} \) has been calculated by using expression:

\[ S_{\text{calc}} = C(n) S\left( ^{1}I_{13/2} - ^{1}I_{15/2} \right) \]

where:

\[ S\left( ^{1}I_{13/2} - ^{1}I_{15/2} \right) = \sum_{i=1}^{i_{\text{max}}} \Omega_i \left| \langle ^{1}I_{13/2} | U^{(i)} | ^{1}I_{15/2} \rangle \right|^2 \]

\[ C(n) = \frac{(n^2 + 2)}{9n} \frac{2\pi^3 e^3}{2\hbar \omega} \exp \left( \frac{-E_i}{k_B T} \right) \]

S is the electric – dipole transition strength, \( U^{(i)} \) are matrix elements and \( \Omega_i \) are Judd-Ofelt parameters. \( S_{\text{calc}} \) was calculated taking account \( \Omega \) parameters from \( ^3 \), \( S_{\text{calc}} = 0.893 \) and \( C(n) = 0.0283 \) for \( \text{YVO}_4 \) (\( n = 2.02 \)). In this calculation it is assumed that all transitions between the Stark components have the same intensity and the same polarisation.

The resulting spectrum is presented in Fig 3 by bold line. It can be seen that the excitation spectrum coincides with both the ESA transition and GSA transition lines. The overlap with the \( \sigma_{\text{GSA}} \) is weaker than with \( \sigma_{\text{ESA}} \). Thus, we conclude that the losses by ESA from \( ^{4}I_{13/2} \) when exciting \( ^{4}S_{3/2} \) luminescence of \( \text{Er}^{3+} \) in \( \text{YVO}_4 \) solid line with \( ^{0}F_{7/2} \) doped fluorozirconate glasses, ESA processes were the principal processes for the upconversion emission near 550 nm.

To determine the absorption cross section for \( ^{4}I_{13/2} - ^{4}I_{15/2} \) transition of \( \text{Er}^{3+} \) in \( \text{YVO}_4 \) we have used the reciprocity method\( ^6 \). This method is based on the relation between absorption cross section \( \sigma_\alpha (\lambda) \) and emission cross section \( \sigma_\text{em} (\lambda) \) by the following relation

\[ \sigma_\text{em} (\lambda) = \frac{Z_{\text{em}}}{Z_{\text{ap}}} \sigma_\alpha (\lambda) \exp \left( \frac{Z_{\text{em}} - E(\lambda)}{k_B T} \right) \]

where: \( Z_{\text{low}}, Z_{\text{up}} \) are the partition functions of lower and upper level, respectively, defined as

\[ Z_{\text{em}} = \sum_{i=1}^{i_{\text{max}}} g_i \exp \left( \frac{-E_i}{k_B T} \right) \]

\[ Z_{\text{ap}} = \sum_{i=1}^{i_{\text{max}}} g_i \exp \left( \frac{-(E_i - E(\lambda))}{k_B T} \right) \]

where: \( g_i (g_i) \) is a degeneration of sublevel, \( E_i (E_f) \) is the energy of the sublevel, \( E_{\text{ZL}} \) is an energy separation between the lowest crystal field components of the upper and lower multiplets, and \( k_B \) is the Boltzmann constant. The ratio \( Z_{\text{em}}/Z_{\text{ap}} \) calculated using the above values is equal to 1.06. The energies of \( E_i \) and \( E_f \) Stark sublevels for \( ^{4}I_{15/2} \) and \( ^{4}I_{13/2} \) were taken from Table 3 in \( ^3 \). Calculated
corresponding \( \sigma \) spectra are also given by solid lines in those figures. The luminescence spectra for \( \pi \) and \( \sigma \) polarisation recorded under excitation by Ti:sapphire laser emitting at 970 nm are presented in Fig. 4b and Fig. 5b. It can be seen that spectra derived by reciprocity method are in a good agreement with luminescence spectra recorded for both \( \pi \) and \( \sigma \) polarisation. From the estimated \( \sigma_\pi (\lambda) \) and \( \sigma_\sigma (\lambda) \) the gain coefficient \( G(\lambda) \) was calculated using formula\(^{10}\):

\[
G(\lambda) = N \left[ P \sigma_\pi (\lambda) - (1 - P) \sigma_\sigma (\lambda) \right]
\]

where \( N \) is the Er\(^{3+} \) concentration, \( P \) is a population inversion parameter defined as a density of ions in upper state divided by \( N \). Results of calculation for several reasonable values of \( P \) are shown in Fig. 6. The presented results are consistent with that presented by F.S. Ermeneux et al.\(^1\) and suggest the possible application of Er:YVO\(_4\) as a laser material operating near 1.6 μm.

4. CONCLUSION

The theoretical approach basis on multiphonon relaxation model cannot predict the experimental temperature dependence of lifetime for the \( ^4S_{3/2} \) level. The participation of the ESA process from \( ^4I_{15/2} \) in upconverted green phenomenon under excitation at 970 nm is appreciable. The emission cross section spectra derived by reciprocity method are consistent with recorded luminescence spectra of \( ^4I_{13/2} - ^4I_{15/2} \) transition for both \( \pi \) and \( \sigma \) polarisation. The positive gain coefficient for \( ^4I_{13/2} - ^4I_{15/2} \) transition suggest the possible application of Er:YVO\(_4\) as a laser material operating near 1.6 μm.

ACKNOWLEDGMENTS

This work is supported by The Polish Committee for Scientific Research under grant No. 8T 11B 021 17

REFERENCES


